### **Digital Transistors (BRT) R1 = 4.7 k** $\Omega$ , **R2 =** $\infty$ **k** $\Omega$

PNP Transistors with Monolithic Bias Resistor Network

### MUN2116, MMUN2116L, MUN5116, DTA143TE, DTA143TM3, NSBA143TF3, NSVMUN5116T1G

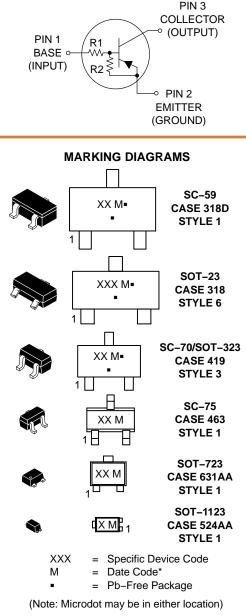
This series of digital transistors is designed to replace a single device and its external resistor bias network. The Bias Resistor Transistor (BRT) contains a single transistor with a monolithic bias network consisting of two resistors; a series base resistor and a base–emitter resistor. The BRT eliminates these individual components by integrating them into a single device. The use of a BRT can reduce both system cost and board space.

#### Features

- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

<b>MAXIMUM RATINGS</b> ( $T_A = 25^{\circ}C$ )					
Rating	Symbol	Max	Unit		
Collector-Base Voltage	V <sub>CBO</sub>	50	Vdc		
Collector-Emitter Voltage	V <sub>CEO</sub>	50	Vdc		
Collector Current – Continuous	۱ <sub>C</sub>	100	mAdc		
Input Forward Voltage	V <sub>IN(fwd)</sub>	30	Vdc		
Input Reverse Voltage	V <sub>IN(rev)</sub>	5	Vdc		

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



**PIN CONNECTIONS** 

\*Date Code orientation may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

See detailed ordering, marking, and shipping information in the package dimensions section on page 2 of this data sheet. NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 2.

### MUN2116, MMUN2116L, MUN5116, DTA143TE, DTA143TM3, NSBA143TF3, NSVMUN5116T1G

#### Table 1. ORDERING INFORMATION

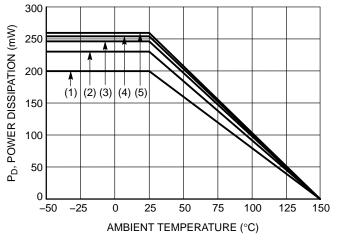
Device	Part Marking	Package	Shipping <sup>†</sup>
MUN2116T1G	6F	SC–59 (Pb–Free)	3000 / Tape & Reel
MMUN2116LT1G, SMMUN2116LT1G	A6F	SOT-23 (Pb-Free)	3000 / Tape & Reel
MUN5116T1G	6F	SC-70/SOT-323 (Pb-Free)	3000 / Tape & Reel
DTA143TET1G	6F	SC-75 (Pb-Free)	3000 / Tape & Reel
DTA143TM3T5G	6F	SOT-723 (Pb-Free)	8000 / Tape & Reel
NSBA143TF3T5G	Q (180°)	SOT-1123 (Pb-Free)	8000 / Tape & Reel
NSVMUN5116T1G	6F	SC-70/SOT-323 (Pb-Free)	3000 / Tape & Reel

#### DISCONTINUED (Note 1)

SMMUN2116LT3G	6F	SOT-23 (Pb-Free)	10000 / Tape & Reel
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+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

1. **DISCONTINUED:** These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on <u>www.onsemi.com</u>.



(1) SC-75 and SC-70/SOT323; Minimum Pad
(2) SC-59; Minimum Pad
(3) SOT-23; Minimum Pad
(4) SOT-1123; 100 mm<sup>2</sup>, 1 oz. copper trace

(5) SOT-723; Minimum Pad

Figure 1. Derating Curve

## MUN2116, MMUN2116L, MUN5116, DTA143TE, DTA143TM3, NSBA143TF3, NSVMUN5116T1G

#### **Table 2. THERMAL CHARACTERISTICS**

Characteristic		Symbol	Max	Unit
THERMAL CHARACTERISTICS (SC-59) (MUN2116)				
Total Device Dissipation $T_A = 25^{\circ}C$	(Note 2) (Note 3)	PD	230 338	mW
Derate above 25°C	(Note 2) (Note 3)		1.8 2.7	mW/°C
Thermal Resistance, Junction to Ambient	(Note 2) (Note 3)	$R_{\thetaJA}$	540 370	°C/W
Thermal Resistance, Junction to Lead	(Note 2) (Note 3)	$R_{\thetaJL}$	264 287	°C/W
Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
THERMAL CHARACTERISTICS (SOT-23) (MMUN2116L)				
Total Device Dissipation $T_A = 25^{\circ}C$	(Note 2) (Note 3)	PD	246 400	mW
Derate above 25°C	(Note 2) (Note 3)		2.0 3.2	mW/°C
Thermal Resistance, Junction to Ambient	(Note 1) (Note 3)	$R_{\thetaJA}$	508 311	°C/W
Thermal Resistance, Junction to Lead	(Note 2) (Note 3)	$R_{ hetaJL}$	174 208	°C/W
Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
THERMAL CHARACTERISTICS (SC-70/SOT-323) (MUN5116)				
Total Device Dissipation $T_A = 25^{\circ}C$	(Note 2) (Note 3)	PD	202 310	mW
Derate above 25°C	(Note 2) (Note 3)		1.6 2.5	mW/°C
Thermal Resistance, Junction to Ambient	(Note 2) (Note 3)	$R_{\thetaJA}$	618 403	°C/W
Thermal Resistance, Junction to Lead	(Note 2) (Note 3)	$R_{\theta JL}$	280 332	°C/W
Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
THERMAL CHARACTERISTICS (SC-75) (DTA143TE)				
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above 25°C	(Note 2) (Note 3) (Note 2)	PD	200 300 1.6	mW mW/°C
Thermal Resistance,	(Note 3) (Note 2)	$R_{ hetaJA}$	2.4 600	°C/W
Junction to Ambient	(Note 3)		400	
Junction and Storage Temperature Range THERMAL CHARACTERISTICS (SOT-723) (DTA143TM3)		T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C
		D		
Total Device Dissipation $T_A = 25^{\circ}C$	(Note 2)	PD	260	mW
Derate above 25°C	(Note 3) (Note 2) (Note 3)		600 2.0 4.8	mW/°C
Thermal Resistance, Junction to Ambient	(Note 2) (Note 3)	$R_{\thetaJA}$	480 205	°C/W
Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

## MUN2116, MMUN2116L, MUN5116, DTA143TE, DTA143TM3, NSBA143TF3, NSVMUN5116T1G

#### **Table 2. THERMAL CHARACTERISTICS**

Characteristic		Symbol	Max	Unit
THERMAL CHARACTERISTICS (SOT-1123) (NSBA143TF3)				
Total Device Dissipation $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	(Note 4) (Note 5) (Note 4) (Note 5)	P <sub>D</sub>	254 297 2.0 2.4	mW mW/°C
Thermal Resistance, Junction to Ambient	(Note 4) (Note 5)	$R_{ hetaJA}$	493 421	°C/W
Thermal Resistance, Junction to Lead	(Note 4)	$R_{ ext{ heta}JL}$	193	°C/W
Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

2. FR-4 @ Minimum Pad.

3. FR-4 @ 1.0 x 1.0 Inch Pad.

FR-4 @ 100 mm<sup>2</sup>, 1 oz. copper traces, still air.
 FR-4 @ 500 mm<sup>2</sup>, 1 oz. copper traces, still air.

#### Table 3. ELECTRICAL CHARACTERISTICS ( $T_A = 25^{\circ}C$ , unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector–Base Cutoff Current $(V_{CB} = 50 \text{ V}, I_E = 0)$	I <sub>CBO</sub>	_	_	100	nAdc
Collector–Emitter Cutoff Current $(V_{CE} = 50 \text{ V}, I_B = 0)$	I <sub>CEO</sub>	_	_	500	nAdc
Emitter–Base Cutoff Current ( $V_{EB} = 6.0 \text{ V}, I_C = 0$ )	I <sub>EBO</sub>	-	_	1.9	mAdc
Collector–Base Breakdown Voltage $(I_C = 10 \ \mu A, I_E = 0)$	V <sub>(BR)</sub> CBO	50	_	-	Vdc
Collector–Emitter Breakdown Voltage (Note 6) $(I_{C} = 2.0 \text{ mA}, I_{B} = 0)$	V <sub>(BR)</sub> CEO	50	_	-	Vdc
ON CHARACTERISTICS					
DC Current Gain (Note 6) ( $I_C = 5.0 \text{ mA}, V_{CE} = 10 \text{ V}$ )	h <sub>FE</sub>	160	250	-	
Collector–Emitter Saturation Voltage (Note 6) $(I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA})$	V <sub>CE(sat)</sub>	-	_	0.25	Vdc
Input Voltage (off) $(V_{CE} = 5.0 \text{ V}, I_C = 100 \mu\text{A})$	V <sub>i(off)</sub>	-	0.6	0.5	Vdc
Input Voltage (on) $(V_{CE} = 0.3 \text{ V}, I_C = 10 \text{ mA})$	V <sub>i(on)</sub>	1.3	0.9	-	Vdc
Output Voltage (on) (V <sub>CC</sub> = 5.0 V, V <sub>B</sub> = 2.5 V, R <sub>L</sub> = 1.0 k $\Omega$ )	V <sub>OL</sub>	_	_	0.2	Vdc
Output Voltage (off) $(V_{CC} = 5.0 \text{ V}, \text{ V}_{B} = 0.25 \text{ V}, \text{ R}_{L} = 1.0 \text{ k}\Omega)$	V <sub>OH</sub>	4.9	_	-	Vdc
Input Resistor	R1	3.3	4.7	6.1	kΩ
Resistor Ratio	R <sub>1</sub> /R <sub>2</sub>	-	-	-	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 6. Pulsed Condition: Pulse Width = 300 msec, Duty Cycle  $\leq 2\%$ .

#### MUN2116, MMUN2116L, MUN5116, DTA143TE, DTA143TM3, NSBA143TF3, NSVMUN5116T1G TYPICAL CHARACTERISTICS MUN2116, MMUN2116L, MUN5116, DTA143TE, DTA143TM3

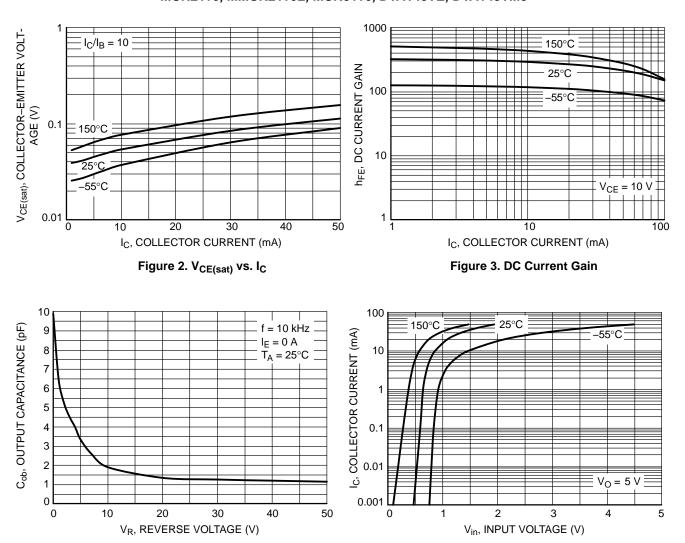


Figure 4. Output Capacitance

Figure 5. Output Current vs. Input Voltage

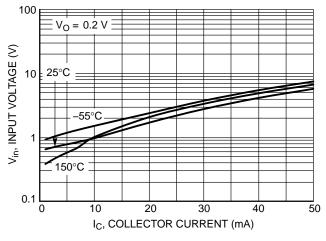
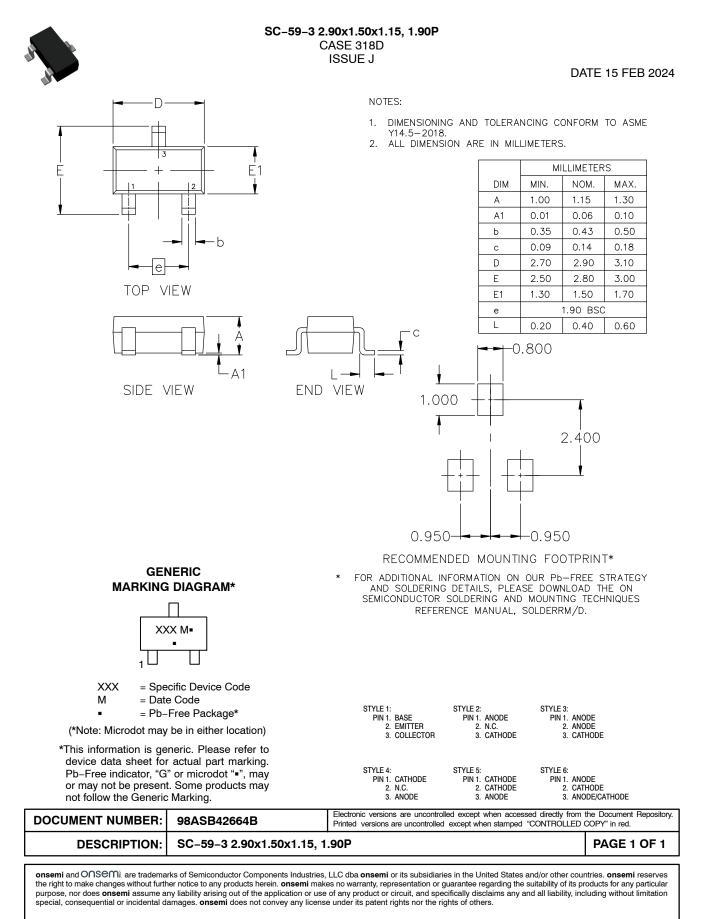


Figure 6. Input Voltage vs. Output Current

#### MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

# 



# semi



#### SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318**

**ISSUE AU** 

DATE 14 AUG 2024









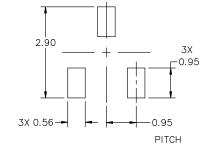




XXX = Specific Device Code М = Date Code

= Pb-Free Package .

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



MILLIMETERS					
DIM	MIN	NOM	МАХ		
А	0.89	1.00	1.11		
A1	0.01	0.06	0.10		
b	0.37	0.44	0.50		
с	0.08	0.14	0.20		
D	2.80	2.90	3.04		
E	1.20	1.30	1.40		
е	1.78	1.90	2.04		
L	0.30	0.43	0.55		
L1	0.35	0.54	0.69		
Ηe	2.10	2.40	2.64		
Т	0°		10°		

NOTES:

DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS: 1.

2. MILLIMETERS.

MILLIME IERS. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE 3.

BASE MATERIAL. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, 4. PROTRUSIONS, OR GATE BURRS.

#### RECOMMENDED MOUNTING FOOTPRINT

\* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **STYLES ON PAGE 2**

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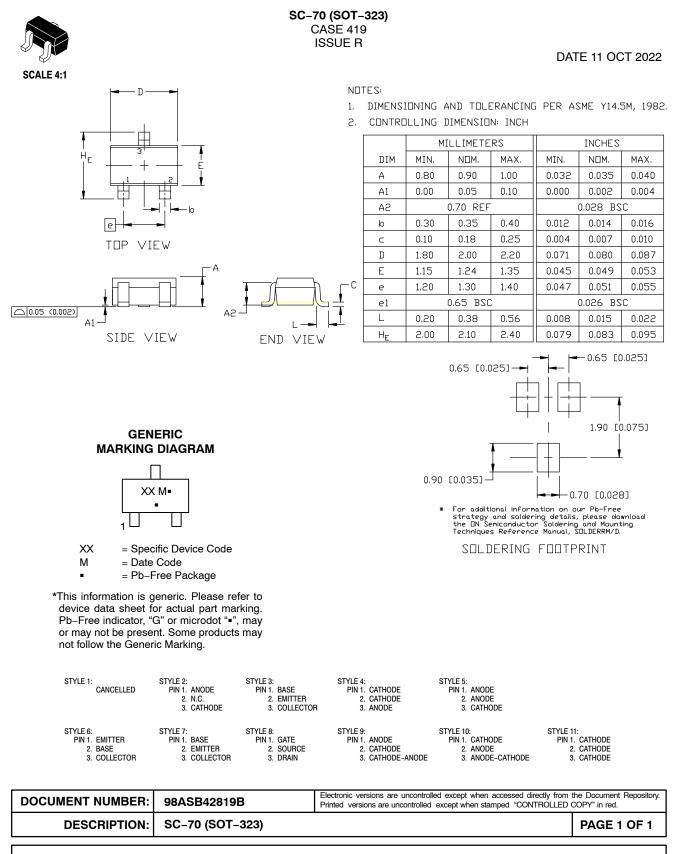
DATE 14 AUG 2024

STYLE 1 THRU 5: CANCELLED	STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR	STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE	ı	
STYLE 9:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1. ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
2. ANODE	2. SOURCE	2. CATHODE	2. CATHODE	2. DRAIN	2. GATE
3. CATHODE	3. GATE	3. CATHODE-ANODE	3. ANODE	3. GATE	3. ANODE
STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	I PIN 1. CATHODE	PIN 1. CATHODE
2. CATHODE	2. CATHODE	2. ANODE	2. CATHODE	2. ANODE	2. ANODE
3. ANODE	3. CATHODE	3. CATHODE	3. ANODE	3. CATHODE-ANODE	3. GATE
STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
2. SOURCE	2. OUTPUT	2. ANODE	2. DRAIN	2. CATHODE	2. ANODE
3. DRAIN	3. INPUT	3. CATHODE	3. SOURCE	3. GATE	3. NO CONNECTION
STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE	STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE				

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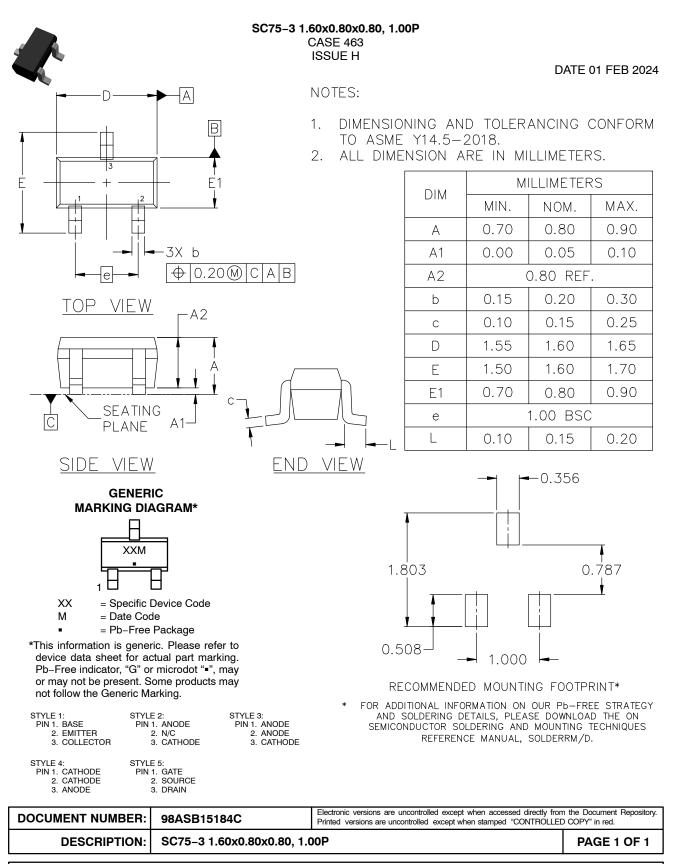
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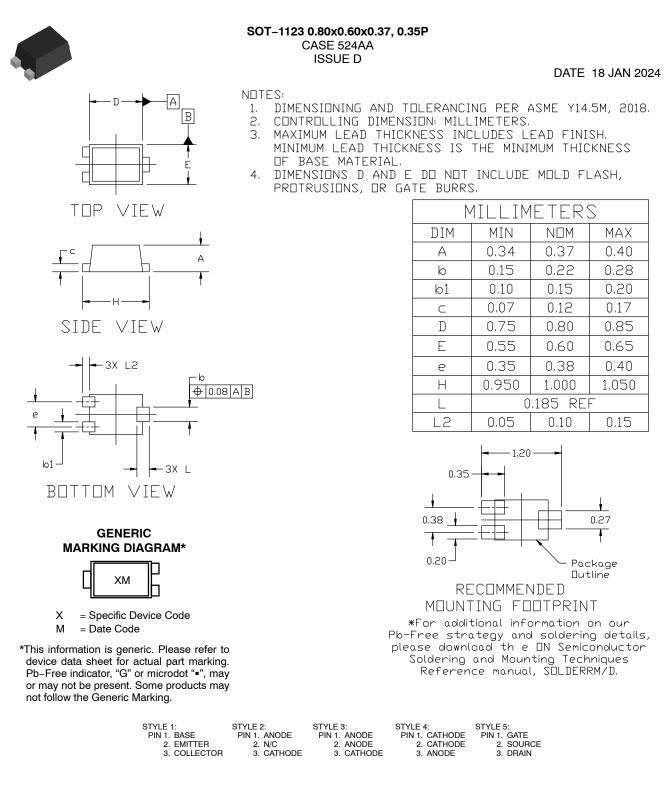
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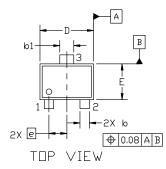


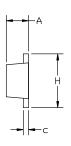
#### SOT-723 1.20x0.80x0.50, 0.40P CASE 631AA ISSUE E

DATE 24 JAN 2024

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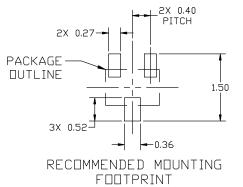
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- 2.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM З. LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, 4. PROTRUSIONS OR GATE BURRS.



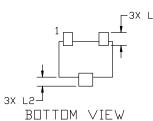


SIDE VIEW

		MILLIMETERS				
	DIM	MIN.	NDM.	MAX.		
1	А	0.45	0.50	0.55		
	b	0.15	0.21	0.27		
	b1	0.25	0.31	0.37		
	С	0.07	0.12	0.17		
	D	1.15	1.20	1.25		
	E	0.75	0.80	0.85		
	e		0.40 BSC			
	Н	1.15	1.20	1.25		
	L		0.29 REF	-		
	L2	0.15	0.20	0.25		



\*For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.



GENERIC **MARKING DIAGRAM\*** 



XX = Specific Device Code = Date Code Μ

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

PIN 1. BASE PIN 2. EMITTER		2. ANODE 2	4: . CATHODE . CATHODE . ANODE	STYLE 5: PIN 1. GATE 2. SOURCE 3. DRAIN		
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